

HA19217MP

High-speed 8-bit A/D Converter with Analog Multiplexer



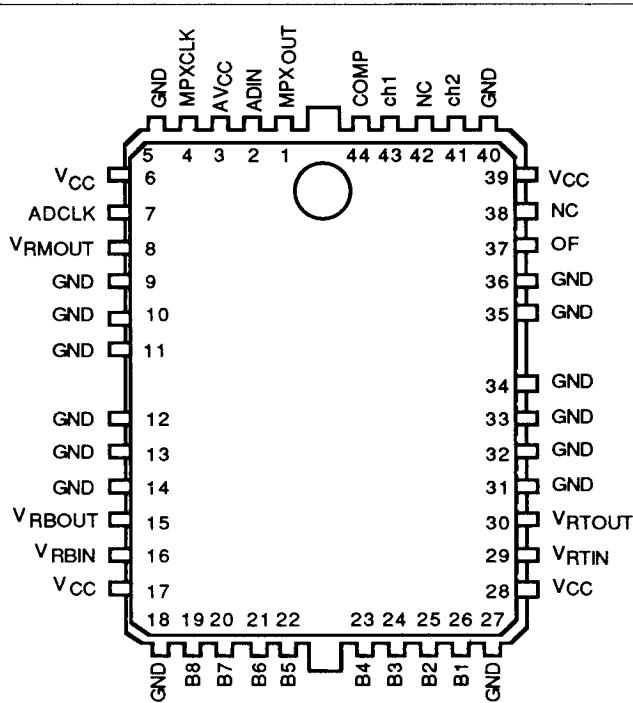
Rev. 0
June 1989
Preliminary

The HA19217 is a monolithic bipolar LSI featuring an on-chip 2-channel analog multiplexer, and is designed for applications that require an 8-bit A/D converter. A parallel type A/D converter means that no sample-and-hold circuit is required for analog input. The digital output level is LS-TTL compatible, while the block input level is TTL, CMOS compatible. The HA19217 is the perfect answer in applications that call for high-speed image processing of video signals.

Features

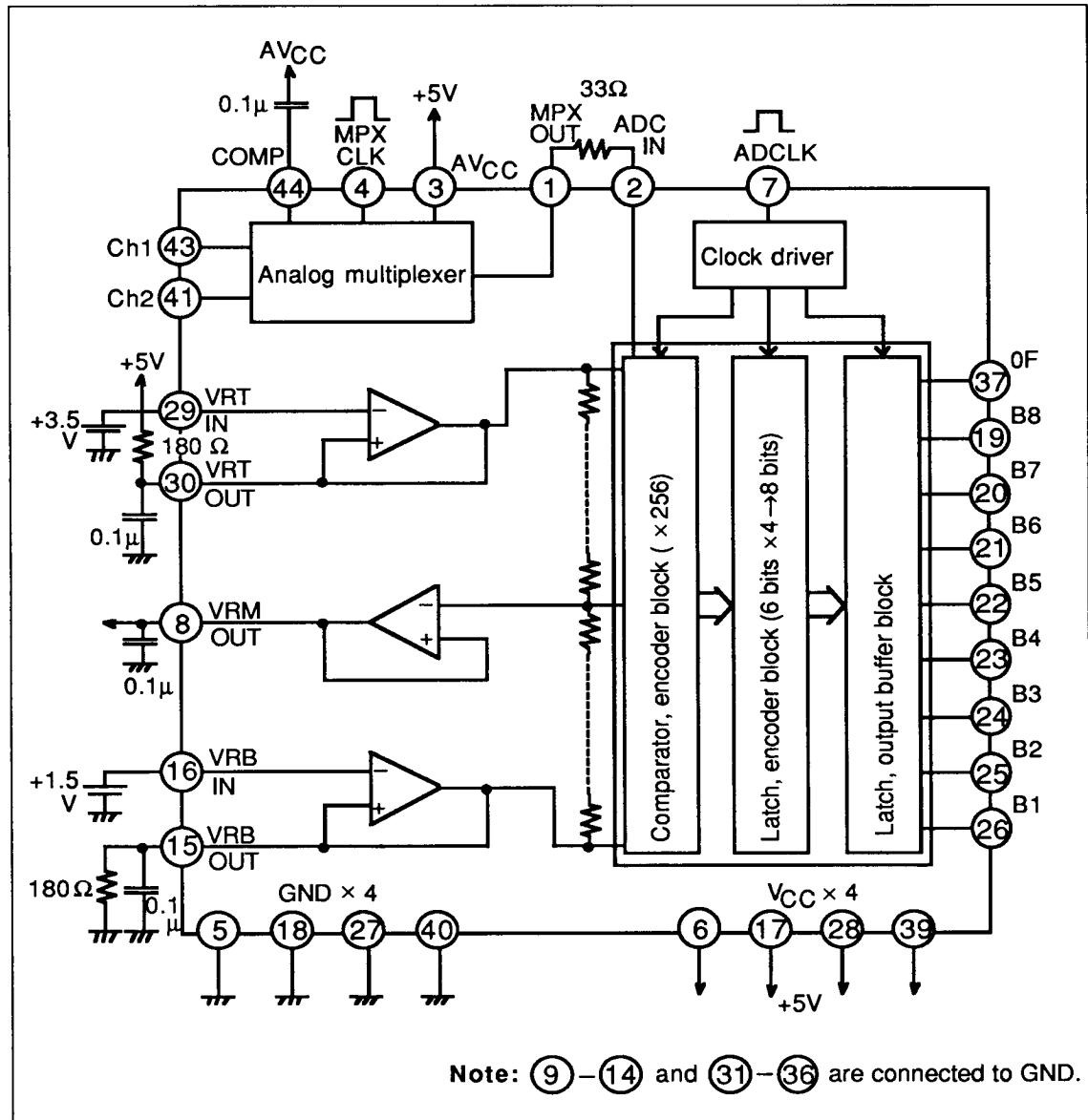
- Resolution 8 bits (with overflow)
- Maximum conversion speed 40Msps (Typ)
- On-chip 2-channel analog multiplexer
- On-chip operational amplifier for reference voltage
- Operating supply voltage +5V single
- Clock input level LS-TTL, CMOS compatible
- Digital output level LS-TTL compatible

Pin Configuration



HA19217MP

Block Diagram



Absolute Maximum Ratings (Ta = 25°C unless otherwise noted)

Item	Symbol	Rated Value	Unit
Supply voltage	V _{CC}	+7.0	V
Supply current	I _{CC}	TBD	mA
Power dissipation	P _T	TBD	mW
Operating temperature	T _{opr}	0 to +70	°C
Storage temperature	T _{stg}	-55 to +125	°C

HA19217MP

Electrical Characteristics

- ADC ($T_a = 25^\circ\text{C}$, $V_{CC} = 5.0\text{V}$, $V_{RTIN} = 3.5\text{V}$, $V_{RBIN} = 1.5\text{V}$, unless otherwise noted)

Item		Symbol	Min	Typ	Max	Unit	Test Condition
Resolution		RES	8	8	8	Bit	
Supply voltage range		V_{CC}	4.5	5.0	5.5	V	
Reference terminal input voltage range	RT	V_{RTIN}	—	3.5	—	V	
	RB	V_{RBIN}	—	1.5	—	V	
Input signal voltage range		V_{IN} (ADC)	V_{RBIN} —0.1	—	V_{RTIN} +0.1	V	
Input dynamic range		V_{RTIN} — V_{RBIN}	—	2.0	—	V	
Supply current		I_{CC} (ADC)	—	92	—	mA	
Reference terminal input current	RT	I_{RTIN}	-20	—	+20	μA	
	RB	I_{RBIN}	-20	—	+20	μA	
Operational amplifier	RT	ΔV_{RT} (OUT – IN)	-15	—	+15	mV	
	RB	ΔV_{RM} (OUT – IN)	-15	—	+15	mV	
Reference strings resistor		R_{str}	—	180	—	Ω	
ADC analog input current		I_{IN} (ADC)	—	70	—	μA	
ADC clock input voltage	H	V_{IH} (ADC)	2.0	—	V_{CC}	V	
	L	V_{IL} (ADC)	0	—	0.8	V	
ADC clock input current	H	I_{IH} (ADC)	—	—	0.4	mA	$V_{IH} = 2.7\text{V}$
	L	I_{IL} (ADC)	-0.4	—	—	mA	$V_{IL} = 0.4\text{V}$
Digital output voltage	H	V_{OH}	2.7	—	—	V	$I_{OH} = -400\mu\text{A}$
	L	V_{OL}	—	—	0.5	V	$I_{OL} = 4\text{mA}$
Midpoint reference voltage level		V_{RM}	-15	—	+15	mV	Offset from $V_{RTOUT} + V_{RBOUT}$
Midpoint reference voltage variation		ΔV_{RM}	-5	—	+5	mV	Output current = $\pm 50\mu\text{A}$

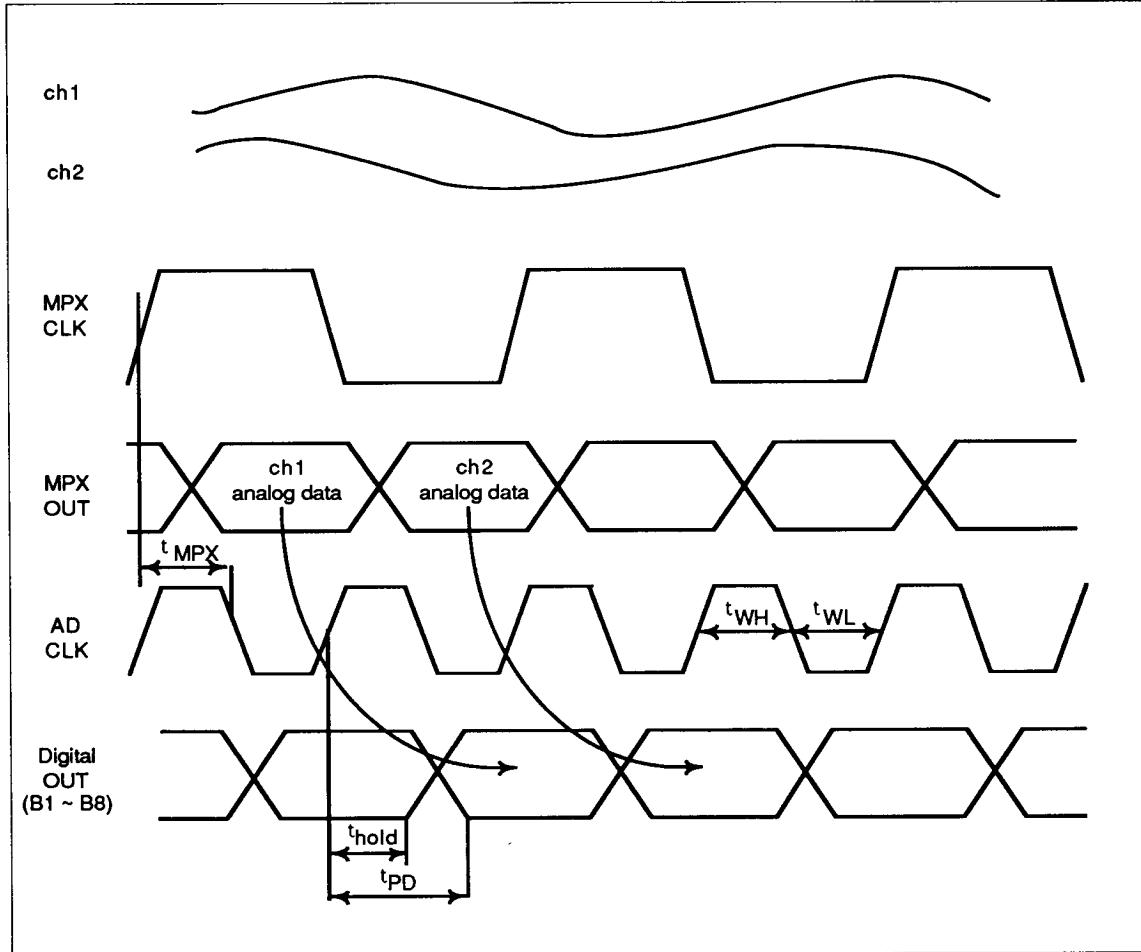
HA19217MP

Item		Symbol	Min	Typ	Max	Unit	Test Condition
Static nonlinearity	Differential	DNL	—	±0.5	—	LSB	
	Integral	INL	—	±0.5	—	LSB	
Maximum conversion speed		f _{CLK}	30	40	—	MspS	
ADC clock pulse width	H	t _{WH}	15	—	—	ns	
	L	t _{WL}	15	—	—	ns	
Digital output delay time		t _{PD}	—	—	20	ns	
Digital output hold time		t _{HOLD}	5	—	—	ns	

• Multiplexer

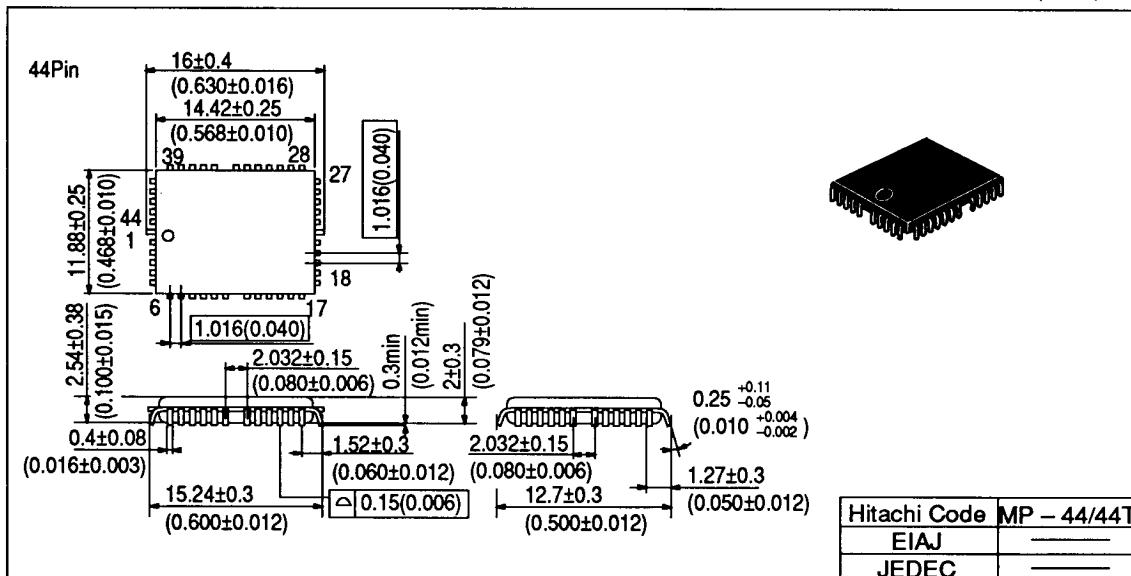
(Ta = 25°C, AVcc = Vcc = 5.0V, V_{RTIN} = 3.5V, V_{RBIN} = 1.5V, 33Ω between MPX_{OUT} and ADC_{IN}, unless otherwise noted)

Item		Symbol	Min	Typ	Max	Unit	Test Condition
Supply voltage range		V _{CC}	4.5	5.0	5.5	V	
Input signal voltage range		V _{IN} (MPX)	1.5	—	3.5	V	
Supply current		I _{CC} (MPX)	—	28	—	mA	
MPX analog input current		I _{IN} (MPX)	—	—	100	μA	
Channel-to-channel offset		V _{ofs} (MPX)	-15	—	+15	mV	Ch1 = Ch2 = 1.5 to 3.5V
MPX output voltage	H	V _{OUT} (1.5V)	—	3.5	—	V	Ch1 or Ch2 = 1.5V
	L	V _{OUT} (3.5V)	—	1.5	—	V	Ch1 or Ch2 = 3.5V
DC gain		Gain	—	0	—	dB	
MPX clock input voltage	H	V _{IH} (MPX)	2.0	—	V _{CC}	V	
	L	V _{IL} (MPX)	0	—	0.8	V	
MPX clock input current	H	I _{IH} (MPX)	—	—	0.4	mA	V _{IH} = 2.7V
	L	I _{IL} (MPX)	-0.4	—	—	mA	V _{IL} = 0.4V
Frequency response		f _{res}	-1.0	—	+1.0	dB	V _{in} = 2V _{p-p} f _{in} = 10MHz (excluding DC gain)
Switching time		t _{MPX}	—	—	25	ns	

Timing Chart

Pachage Outline

Unit: mm (inch)



When using this document, keep the following in mind:

1. This document may, wholly or partially, be subject to change without notice.
2. All rights are reserved: No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without Hitachi's permission.
3. Hitachi will not be held responsible for any damage to the user that may result from accidents or any other reasons during operation of the user's unit according to this document.
4. Circuitry and other examples described herein are meant merely to indicate the characteristics and performance of Hitachi's semiconductor products. Hitachi assumes no responsibility for any intellectual property claims or other problems that may result from applications based on the examples described herein.
5. No license is granted by implication or otherwise under any patents or other rights of any third party or Hitachi, Ltd.
6. MEDICAL APPLICATIONS: Hitachi's products are not authorized for use in MEDICAL APPLICATIONS without the written consent of the appropriate officer of Hitachi's sales company. Such use includes, but is not limited to, use in life support systems. Buyers of Hitachi's products are requested to notify the relevant Hitachi sales offices when planning to use the products in MEDICAL APPLICATIONS.



Hitachi, Ltd.

New Marunouchi Bldg., 5-1, Marunouchi 1 chome, Chiyoda-ku, Tokyo 100, Japan

Tel: Tokyo (03) 212-1111

Telex: J22395, J22432, J24491, J26375 (HITACY)

Cable: HITACY TOKYO

For further information write to:

Hitachi America, Ltd.

Semiconductor & IC Div.

2000 Sierra Point Parkway

Brisbane, CA. 94005-1819,

U S A

Tel: 415-589-8300

Fax: 415-583-4207

Hitachi Europe GmbH

Electronic Components Div.

Central Europe Headquarters

Hans-Pinsel-Straße 10A,

8013 Haar bei München,

West Germany

Tel: 089-46140

Fax: 089-463068

Hitachi Europe Ltd.

Electronic Components Div.

Northern Europe Headquarters

21 Upton Road,

Watford, Herts WD1 7TB,

United Kingdom

Tel: 0923-246488

Fax: 0923-224422

Hitachi Asia (Hong Kong) Ltd.

Unit 512-513, North Tower,

World Finance Centre,

Harbour City, Canton Road,

Tsimshatsui, Kowloon,

Hong Kong

Tel: 852-3-7359218

Fax: 852-3-7306071